## NSN 5962-01-506-7265

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View Online at https://aerobasegroup.com/nsn/5962-01-506-7265

## **Body Length:**

Between 0.850 inches and 0.930 inches

## Body Width:

Between 0.240 inches and 0.295 inches

## **Body Height:**

Between 0.160 inches and 0.180 inches

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **End Application:**

Used inf-15 an/apg-63 radar

## Features Provided:

Electrostatic sensitive and hermetically sealed and monolithic and positive outputs and high speed and bipolar and programmed and

w/decoded output and 3-state output

#### **Inclosure Material:**

Ceramic and glass

## Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Transistor-transistor logic

#### Input Circuit Pattern:

12 input

#### **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

5.5 volts power source

## **Time Rating Per Chacteristic:**

85.00 nanoseconds propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level output

## Memory Device Type:

Rom

#### **Memory Capacity:**

Memory 1024 word x 4 bit

## Test Data Document:

82577-932883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### **Terminal Type And Quantity:**

18 printed circuit

### Shelf Life:

N/a

#### Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

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